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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/677,007	09/30/2003	Tingkai Li	SLA 0793	7277	
27518	7590 05/31/2005		EXAMINER		
DAVID C RIPMA, PATENT COUNSEL			TALBOT, BRIAN K		
SHARP LABORATORIES OF AMERICA 5750 NW PACIFIC RIM BLVD		RICA	ART UNIT	PAPER NUMBER	
CAMAS, WA			1762		
			DATE MAILED: 05/31/200	5	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)		h
	10/677,007	LI ET AL.		
Office Action Summary	Examiner	Art Unit		
	Brian K. Talbot	1762		
The MAILING DATE of this communication appe			ress	
Period for Reply				
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period wi - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a r within the statutory minimum of thir rill apply and will expire SIX (6) MON cause the application to become AE	reply be timely filed ty (30) days will be considered timely. ITHS from the mailing date of this com 3ANDONED (35 U.S.C. § 133).	ımunication.	
Status				
1)⊠ Responsive to communication(s) filed on 30 Se	eptember 2003.			
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ This	action is non-final.			
3) Since this application is in condition for allowan	•	• •	merits is	
closed in accordance with the practice under E	x parte Quayle, 1935 C.D	). 11, 453 O.G. 213.		
Disposition of Claims				
4)⊠ Claim(s) <u>1-16</u> is/are pending in the application.				
4a) Of the above claim(s) is/are withdraw				
5) Claim(s) is/are allowed.				
6)⊠ Claim(s) <u>1-16</u> is/are rejected.				
7) Claim(s) is/are objected to.				
8) Claim(s) are subject to restriction and/or	r election requirement.			
Application Papers				
9) The specification is objected to by the Examiner	r.			
10) The drawing(s) filed on is/are: a) acce		by the Examiner.		
Applicant may not request that any objection to the o	· · · · · · · · · · · · · · · · · · ·	-		
Replacement drawing sheet(s) including the correction	ion is required if the drawing	(s) is objected to. See 37 CFF	R 1.121(d).	
11) The oath or declaration is objected to by the Exa	aminer. Note the attached	d Office Action or form PTC	<b>)</b> -152.	
Priority under 35 U.S.C. § 119				
12) ☐ Acknowledgment is made of a claim for foreign	priority under 35 LLS C 4	S 119(a)-(d) or (f)		
a) All b) Some * c) None of:	p.1.511ty and 01 0.0,0.	· · · · · · · · · · · · · · · · · · ·		
1. Certified copies of the priority documents	s have been received.			
2. Certified copies of the priority documents		application No.		
3.☐ Copies of the certified copies of the priori	•	· · · · · · · · · · · · · · · · · · ·	tage	
application from the International Bureau				į
* See the attached detailed Office action for a list of	of the certified copies not	received.		
Attachment(s)				
1) Notice of References Cited (PTO-892)	4) Interview S	Summary (PTO-413)		
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)		s)/Mail Date		
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)		nformal Patent Application (PTO-	1410	- 1

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1. Claims 1-16 remain in the application.

## Claim Rejections - 35 USC § 112

2. The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 1-16 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

The term "thin" in claims 1 and 9 is a relative term that renders the claim indefinite. The term "thin" is not defined by the claim, the specification does not provide a standard for ascertaining the requisite degree, and one of ordinary skill in the art would not be reasonably apprised of the scope of the invention. The term "completing" is vague and indefinite. In is unclear what the term "completing" encompasses.

With respect to claims 2,3,10 and 11, the phrase "said preparing step includes forming an oxide layer/high-k oxide on the silicon substrate" is confusing. Should this recite in the "depositing" step or is there an oxide layer formed first and then atop this layer an indium-containing layer is formed? Clarification is requested.

The term "high-k" in claim 3 and 11 is a relative term that renders the claim indefinite.

The term "high-k" is not defined by the claim, the specification does not provide a standard for

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ascertaining the requisite degree, and one of ordinary skill in the art would not be reasonably apprised of the scope of the invention.

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With respect to claim 5 and 13, the phrase "forming a silica dioxide trench structure" is unclear. How is this performed from etching the indium-containing film? Where does the "silicon dioxide" comp from when the substrate is silicon and the coating is indium-containing? Claims 4,6-9,12 and 14-16 are rejected as being dependent upon a rejected base claim.

## **Double Patenting**

3. Claims 1-16 are provisionally rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 1-18 of copending Application No. 10/676,983 and claims 1-19 of copending Application No. 10/780,919. Although the conflicting claims are not identical, they are not patentably distinct from each other because the claims recite forming an indium oxide film on a silicon substrate, etching or patterning the indium oxide film, forming a ferroelectric film of PGO thereon, and completing the device.

This is a provisional obviousness-type double patenting rejection because the conflicting claims have not in fact been patented.

## Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

Claims 1-5 and 9-13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Li et al. (6,825,519) in combination with Shepherd (5,003,428).

Li et al. (6,825,519) teaches selectively depositing PGO thin film to form a ferroelectric device. A silicon oxide layer is formed on a silicon substrate, a bottom electrode is formed and patterned thereon, a PGO layer is applied, annealed and a top electrode is formed to complete the device (abstract, col. 1, lines 40-60).

Li et al. (6,825,519) fails to teach a patterned indium oxide layer as the bottom electrode.

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Shepherd (5,003,428) teaches electrodes for ceramic oxide capacitors. Shepherd (5,003,428) teaches that indium oxide and indium tin oxide are used as materials for thin film ferroelectric ceramic capacitors (col. 2, lines 40-50).

Therefore it would have been obvious for one skilled in the art at the time the invention was made to have substituted the electrode material of Li et al. (6,825,519) process by incorporating indium oxide for the electrode material as evidenced Shepherd (5,003,428) with the expectation of achieving similar success.

Claims 7,8,15 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Li et al. (6,825,519) in combination with Shepherd (5,003,428) further in combination with Li et al. (6,664,116).

Features described above are incorporated here.

Li et al. (6,825,519) in combination with Shepherd (5,003,428) fail to teach the claimed processing parameters for forming the PGO film.

Li et al. (6,664,116) teaches the claimed processing parameters for forming the PGO film (col. 2, line 10 - col. 3, line 50).

Therefore it would have been obvious for one skilled in the art at the time the invention was made to have modified Li et al. (6,825,519) in combination with Shepherd (5,003,428) by forming the PGO film as detailed by Li et al. (6,664,116) with the expectation of achieving similar results.

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Claims 6 and 14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Li et al. (6,825,519) in combination with Shepherd (5,003,428).

Features described above are incorporated here.

Li et al. (6,825,519) in combination with Shepherd (5,003,428) fail to teach the claimed processing parameters for forming the In2O3 film.

While the Examiner acknowledges this fact, it is the Examiner's position that sputtering indium oxide films are conventional in the art and the processing parameters would be a matter of design choice of one practicing in the art dependent upon the desired final product.

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Brian K. Talbot whose telephone number is (571) 272-1428. The examiner can normally be reached on Monday-Friday 6AM-3PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Timothy H. Meeks can be reached on (571) 272-1423. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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Brian K Talbot Primary Examiner

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BKT